

Silicon PNP Darlington Power Transistors

2SB1624

DESCRIPTION

- With TO-3PN package
- Complement to type 2SD2493

APPLICATIONS

- Audio ,regulator and general purpose

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter

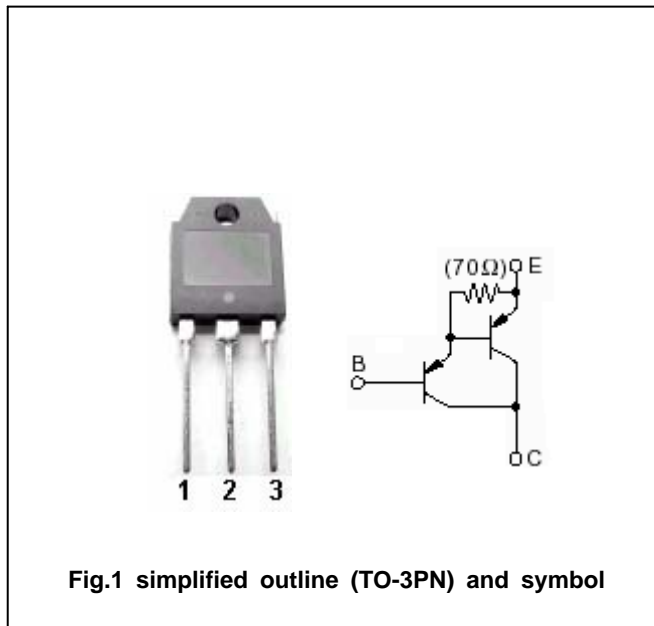


Fig.1 simplified outline (TO-3PN) and symbol

Absolute maximum ratings(Ta= )

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V <sub>CBO</sub>	Collector-base voltage	Open emitter	-110	V
V <sub>CEO</sub>	Collector-emitter voltage	Open base	-110	V
V <sub>EBO</sub>	Emitter-base voltage	Open collector	-5	V
I <sub>C</sub>	Collector current		-6	A
I <sub>B</sub>	Base current		-1	A
P <sub>C</sub>	Collector power dissipation	T <sub>C</sub> =25	60	W
T <sub>j</sub>	Junction temperature		150	
T <sub>stg</sub>	Storage temperature		-55~150	

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**CHARACTERISTICS**

Tj=25 unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_C=-30mA ; I_B=0$	-110			V
$V_{CEsat}$	Collector-emitter saturation voltage	$I_C=-5A ; I_B=-5mA$			-2.5	V
$V_{BEsat}$	Base-emitter saturation voltage	$I_C=-5A ; I_B=-5mA$			-3.0	V
$I_{CBO}$	Collector cut-off current	$V_{CB}=-110V ; I_E=0$			-100	$\mu A$
$I_{EBO}$	Emitter cut-off current	$V_{EB}=-5V ; I_C=0$			-100	$\mu A$
$h_{FE}$	DC current gain	$I_C=-5A ; V_{CE}=-4V$	5000			
$C_{ob}$	Output capacitance	$I_E=0 ; V_{CB}=-10V ; f=1MHz$		110		pF
$f_T$	Transition frequency	$I_C=-0.5A ; V_{CE}=-12V$		100		MHz

Switching times

$t_{on}$	Turn-on time	$I_C=-5A ; R_L=6\Omega$ $I_{B1}=-I_{B2}=-5mA$ $V_{CC}=-30V$		1.1		$\mu s$
$t_s$	Storage time			3.2		$\mu s$
$t_f$	Fall time			1.1		$\mu s$

◆  **$h_{FE}$  Classifications**

O	P	Y
5000-12000	6500-20000	15000-30000

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PACKAGE OUTLINE

